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Substitute for form 1449A/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

Co	emplete if Known
Application Number	10/585,582
Filing Date	July 10, 2006
First Named Inventor	Alexander FINKELSTEIN
Group Art Unit	2891 Confirmation No. 6641
Examiner Name	Matthew L. REAMES
Attorney Docket Number	FINKELSTEIN=1

			U.S. PA	TENT DOCUMENTS	_
Examiner	Cite No.1	Document Number Number-Kind Code ^{2 (if known)}	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
	AA	US- 6,355,953 B1	03-12-2002	George KIRCZENOW	
	AB	US-2003/0075772 A1	04-24-2003	Alexander EFROS et al.	
		US-			
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		NON PATENT LITERATURE DOCUMENTS	OTHER INFOR	RMATION			
Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published					
	AC	S. A. WOLF et al., "Spintronics: A Spin-Based Electronics Vision for the Future", SCIENCE, Vol. 294, pp. 1488 - 1495, November 16, 2001					
	AD	H. OHNO et al., "Semiconductor Spin Electronics", JSAP Intern	ational, Mo. 5, pp.	4-13, January 2002.			
ļ	AE Gary PRINZ, "Magnetoelectronics", SCIENCE, Vol. 282, pp. 1660-1663, November 27, 1998.						
	AF Mark JOHNSON et al., "Interfacial Charge-Spin Coupling: Injection and Detection of Spin Magnetization in Metals", Vol. 55, No. 17, pp. 1790-1793, October 21, 1985.						
	AG	R. FIEDERLING et al., "Injection and Detection of a spin-polari, Vol. 402, pp. 787-789, December 16, 1999.	zed current in a lig	ht-emitting diode", <u>NATURE,</u>			
	AH	Y. OHNO et al., "Electrical spin injection in a ferromagnetic semiconductor heterostructure". NATURE, Vol. 402, pp. 790-792, December 16, 1999.					
	Al	Vladimir Ya. KRAVCHENO et al., "Spin inection into a ballistic semiconductor microstructure", Physical Review B, Vol. 67, pp. 121310-1 - 121310-4, 2003.					
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Exami Signat		/Matthew Reames/	Date Considered	09/28/2009			

* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. ¹ Applicant's unique citation designation number (optional). ² See Kind Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

Receipt, date: 02/23/2007

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Substitute for form 1449A/PTO		Complete if Known					
Substitute for form 1443/47 TO				Application Number	10/585,	10/585,582	
INFORMATION DISCLOSURE				Filing Date	July 10, 2006		
STATEMENT BY APPLICANT		LICANT	First Named Inventor	Alexander FINKELSTEIN			
OTATEMENT BY ATTEMANT			2.07.111	Group Art Unit	2891	Confirmation No. 6641	
(use as many sheets as necessary)			Examiner Name	Matthew L. REAMES			
Sheet	2	of	3	Attorney Docket Number	FINKEL	STEIN=1	
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		NON PATENT LITERATURE DOCUMENTS /OTHER INFORMATION	
Examiner nitials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T²
		Yu A. BYCHKOV et al., "Oscillatory effects and the magnetic susceptibility of carriers in inversion layers", <u>J. Phys. C. Solid State Phys.,</u> Vol. 17, pp. 6039-6045, 1984.	
		J. LUO et al., "Effects of inversion asymmetry on electron energy band structures in GaSb/lnAs/GaSb quantum wells", Phys. Review B, Vol. 41, No. 11, pp. 7685-7693, April 15, 1990.	_
	AN	Simon M. SZE, "Semiconductor Devices: Physics and Technology", Wiley Text Books, 2 nd Edition, pp. 246-253 and 332-368, September 2001.	
	AO	Y. SATO et al., "Large spontaneous spin splitting in gate-controlled two-dimensional electron gases at normal In _{0.75} Ga _{0.25} As/In _{0.75} Al _{0.25} As heterojunctions". <u>Journal of Applied Physics</u> , Vol 89, No. 12 pp. 8017-8021, June 15, 2001.	
		P. M. MORSE et al., "Methods of Theoretical Physics I", Chapter 12.2 Distribution Functions for Diffusion Problems, pp. 1606-1638, June 1953.	
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	AT	Sanker Das. SARMA, "Spintronics", American Scientist, Vol. 89, pp. 516, November 2001.	
	AU	I. I. RABI, "Space Quantization in a Gyrating Magnetic Field", Physical Review, Vol. 51, pp. 652-654, April 15, 1937.	
	AV	J. SPECTOR et al., "Control of ballistic electrons in macroscopic two-dimensional electron systems", Appl. Phys. Letters, Vol. 56, No. 10, pp. 967-969, March 5, 1990.	

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Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of ar magazine, journal, serial, symposium, catalog, etc.), date, page(s), volur published			T²		
	AW	L. W. MOLENKAMP et al., "Electron-beam collimation with a qu No. 2, pp. 1274-1277, January 15, 1990.	antum point conte	act", <u>Physical Review B,</u> Vol. 41,			
_	AX	Yu A. BYCHKOV et al., "Properties of a 2D electron gas with lift No. 2, pp. 78-81, January 25, 1984.	ed spectral deger	neracy", <u>JETP Letters,</u> Vol. 39,			
	AY	S. DATTA et al., "Electronic analog of the electro-optic modulate 665-667, February 12, 1990.	or", Applied Physic	cs Letters, Vol. 56, No. 7, pp.			
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	ВА	B. DAS et al., "Evidence for spin-splitting in In _x Ga _{1-x} As/In _{0.52} AI _{0.4} B, Vol. 39, No. 2, pp. 1411-1414, January 15, 1989.	[®] As heterostructui	es as B→0", <u>Physical Review</u>			
	вв	J. NITTA et al., "Gate Control of Spin-Orbit Interaction in an Inve Physical Review Letters, Vol. 78, No. 7, pp. 1335-1338, Februar		s/In _{0.52} AI _{0.48} As Heterostructure",			
	ВС	G. ENGELS et al., "Experimental and theoretical approach to suggested and the suggested and					
	BD	S. J. PAPADAKIS et al., "Spin-splitting in GaAs two-dimensional holes", Physica E, Vol. 9, pp. 31-39, 2001.					
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